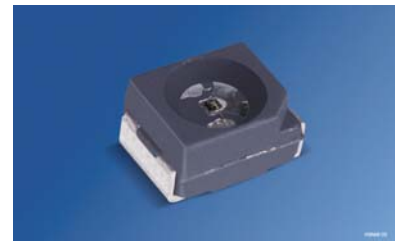


Rote Lumineszenzdiode
Red Emitter
Lead (Pb) Free Product - RoHS Compliant

SFH 4272



Wesentliche Merkmale

- Schwarz eingefärbtes TOPLED-Gehäuse
- Typische Emissionswellenlänge 645nm
- Verbesserte Abbildungseigenschaften durch Absorption der Seitenstrahlung
- Größe der Leuchtquelle 200µm x 200µm
- Feuchte-Empfindlichkeitsstufe 2 nach JEDEC Standard J-STD-020C

Features

- Black coloured TOPLED-package
- Typical Peakwavelength 645nm
- Improved imaging characteristics due to absorption of side emission
- Size of emitting area 200µm x 200µm
- Moisture sensitivity level 2 according to JEDEC Standard J-STD-020C

Anwendungen

- Miniaturlichtschranken und Lichtschranken über große Entfernungen
- Industrieelektronik
- „Messen/Steuern/Regeln“
- Automobiltechnik
- Sensorik
- Alarm- und Sicherungssysteme

Applications

- Miniature and long distance photointerrupters
- Industrial electronics
- For drive and control circuits
- Automotive technology
- Sensor technology
- Alarm and safety equipment

| Typ Type | Bestellnummer Ordering Code | Strahlstärkegruppierung¹⁾ ($I_F = 20 \text{ mA}$, $t_p = 20 \text{ ms}$) Radiant Intensity Grouping¹⁾ $I_e \text{ (mW/sr)}$ |
|---------------------------|--|--|
| SFH 4272 | Q65110A2522 | > 0.16 (typ. 0.35) |

¹⁾ gemessen bei einem Raumwinkel $\Omega = 0.01 \text{ sr}$ / measured at a solid angle of $\Omega = 0.01 \text{ sr}$

Grenzwerte ($T_A = 25\text{ °C}$)

Maximum Ratings

| Bezeichnung Parameter | Symbol Symbol | Wert Value | Einheit Unit |
|---|-------------------|----------------|-----------------|
| Betriebs- und Lagertemperatur Operating and storage temperature range | $T_{op}; T_{stg}$ | - 40 ... + 100 | °C |
| Sperrspannung Reverse voltage | V_R | 5 | V |
| Durchlassstrom Forward current | I_F | 30 | mA |
| Stoßstrom, $\tau = 10\ \mu\text{s}$, $D = 0$ Surge current | I_{FSM} | 1 | A |
| Verlustleistung Power dissipation | P_{tot} | 80 | mW |
| Wärmewiderstand Sperrschicht - Umgebung bei Montage auf FR4 Platine, Padgröße je $16\ \text{mm}^2$ Thermal resistance junction - ambient mounted on PC-board (FR4), padsize $16\ \text{mm}^2$ each | R_{thJA} | 500 | K/W |
| Wärmewiderstand Sperrschicht - Lötstelle bei Montage auf Metall-Block Thermal resistance junction - soldering point, mounted on metal block | R_{thJS} | 280 | K/W |

Kennwerte ($T_A = 25\text{ °C}$)

Characteristics

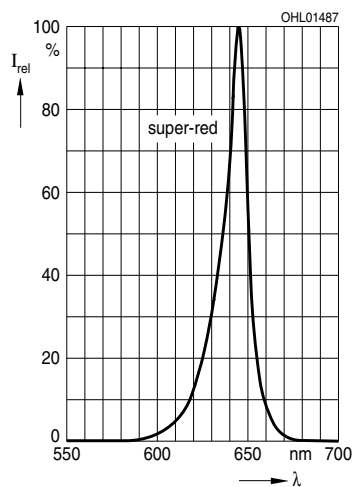
| Bezeichnung Parameter | Symbol Symbol | Wert Value | Einheit Unit |
|--|------------------------------|------------------|-----------------|
| Wellenlänge der Strahlung Wavelength at peak emission $I_F = 20\text{ mA}$, $t_p = 20\text{ ms}$ | λ_{peak} | 645 | nm |
| Spektrale Bandbreite bei 50% von I_{max} Spectral bandwidth at 50% of I_{max} $I_F = 20\text{ mA}$ | $\Delta\lambda$ | 16 | nm |
| Abstrahlwinkel Half angle | φ | ± 60 | Grad deg. |
| Aktive Chipfläche Active chip area | A | 0.04 | mm ² |
| Abmessungen der aktiven Chipfläche Dimensions of the active chip area | $L \times B$ $L \times W$ | 0.2×0.2 | mm ² |
| Durchlassspannung Forward voltage $I_F = 20\text{ mA}$, $t_p = 20\text{ ms}$ | V_F | $2.0 (\leq 2.5)$ | V |
| Sperrstrom Reverse current $V_R = 5\text{ V}$ | I_R | $0.01 (\leq 10)$ | μA |
| Gesamtstrahlungsfluss Total radiant flux $I_F = 20\text{ mA}$, $t_p = 20\text{ ms}$ | Φ_e | 1 | mW |
| Temperaturkoeffizient von I_e bzw. Φ_e , $I_F = 20\text{ mA}$ Temperature coefficient of I_e or Φ_e , $I_F = 20\text{ mA}$ | TC_I | - 0.5 | %/K |
| Temperaturkoeffizient von V_F , $I_F = 20\text{ mA}$ Temperature coefficient of V_F , $I_F = 20\text{ mA}$ | TC_V | - 2 | mV/K |
| Temperaturkoeffizient von λ , $I_F = 20\text{ mA}$ Temperature coefficient of λ , $I_F = 20\text{ mA}$ | TC_λ | + 0.14 | nm/K |

Strahlstärke I_e in Achsrichtung (gemessen bei einem Raumwinkel $\Omega = 0.01\text{ sr}$)Radiant Intensity I_e in Axial Direction (at a solid angle of $\Omega = 0.01\text{ sr}$)

| Bezeichnung Parameter | Symbol | Werte Values | Einheit Unit |
|--|--------|--------------------|-----------------|
| Strahlstärke Radiant intensity $I_F = 20\text{ mA}$, $t_p = 20\text{ ms}$ | I_e | > 0.16 (typ. 0.35) | mW/sr |

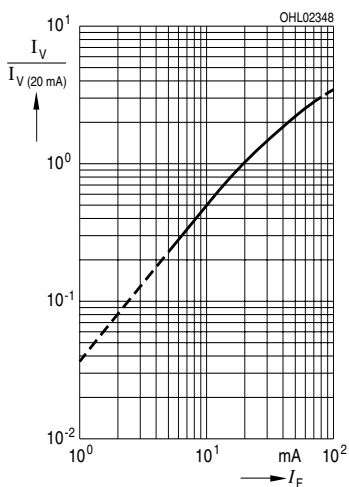
Relative Spectral Emission

$I_{rel} = f(\lambda)$



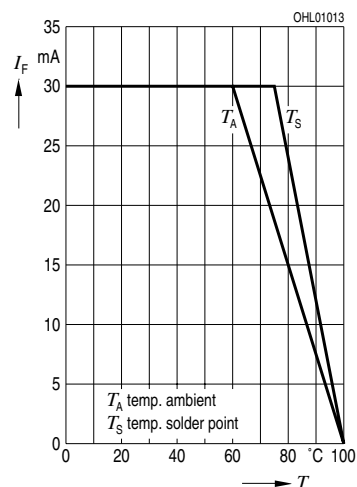
Radiant Intensity

$I_e / I_{e(20\text{ mA})} = f(I_F)$



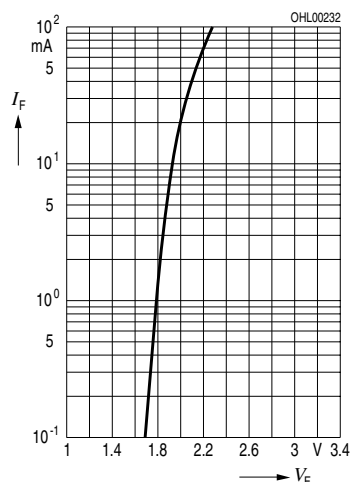
Max. Permissible Forward Current

$I_F = f(T_A)$



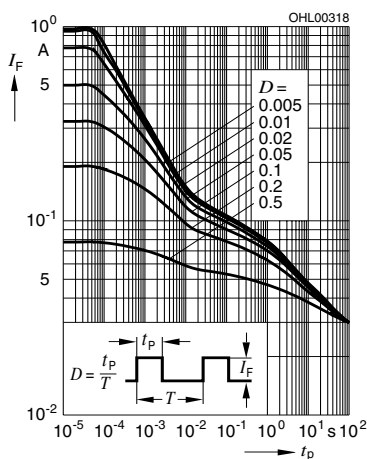
Forward Current

$I_F = f(V_F)$ single pulse, $t_p = 20 \mu\text{s}$



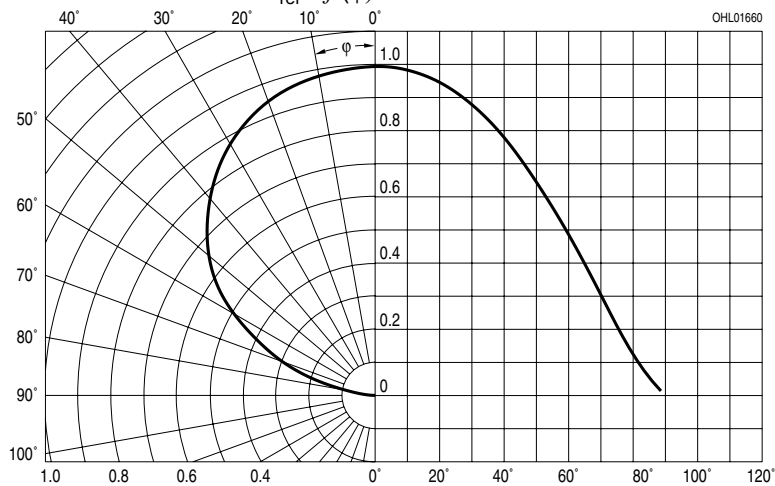
Permissible Pulse Handling Capability

$I_F = f(t_p, T_A = 25^\circ\text{C})$
duty cycle $D = \text{parameter}$

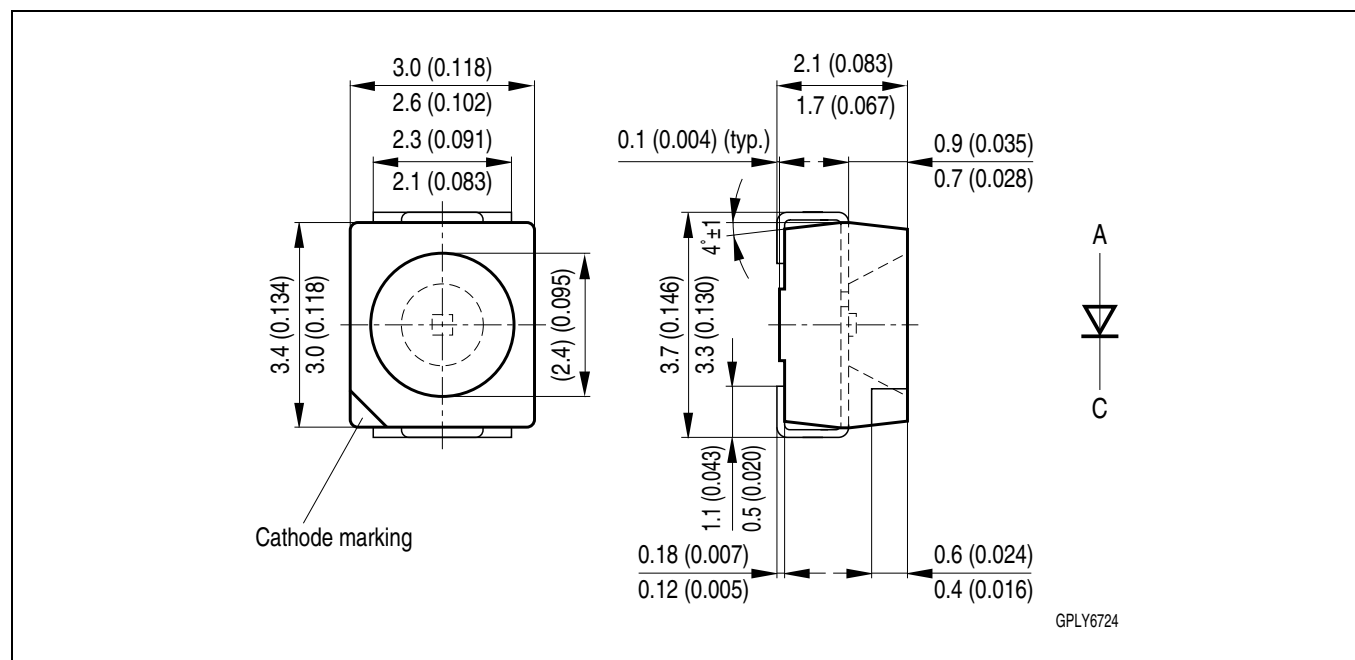


Radiation Characteristics

$I_{rel} = f(\varphi)$



Maßzeichnung Package Outlines

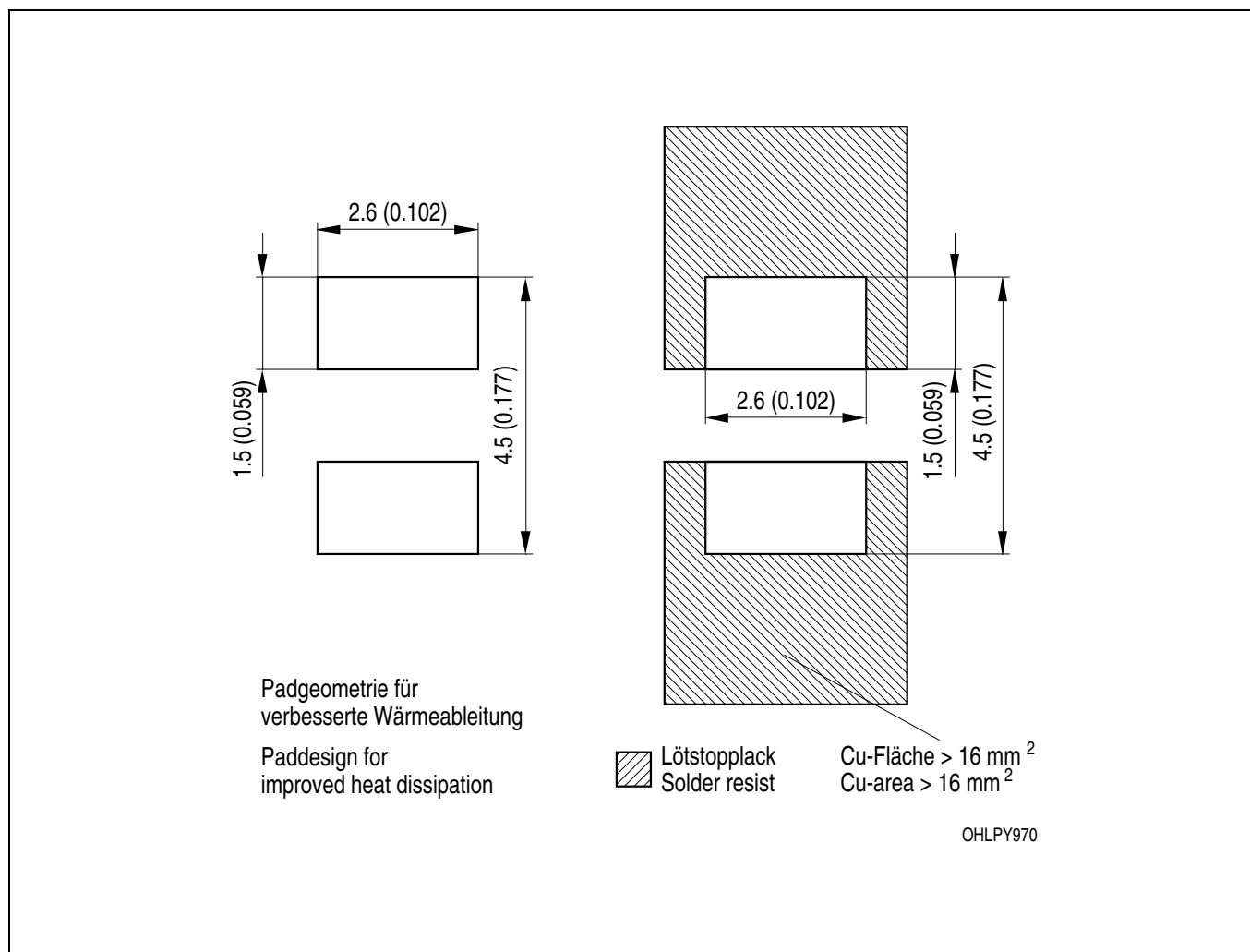


Maße in mm (inch) / Dimensions in mm (inch).

| | |
|--|---|
| Gehäuse / Package | TOPLED®, klarer Verguss / TOPLED®, clear resin |
| Anschlussbelegung Pin configuration | abgeschrägte Ecke: Kathode beveled edge: Cathode |
| Farbe Color | schwarz black |
| Brechungsindex Verguss Refractive index resin | 1.53 1.53 |

Empfohlenes Lötpaddesign
Recommended Solder Pad

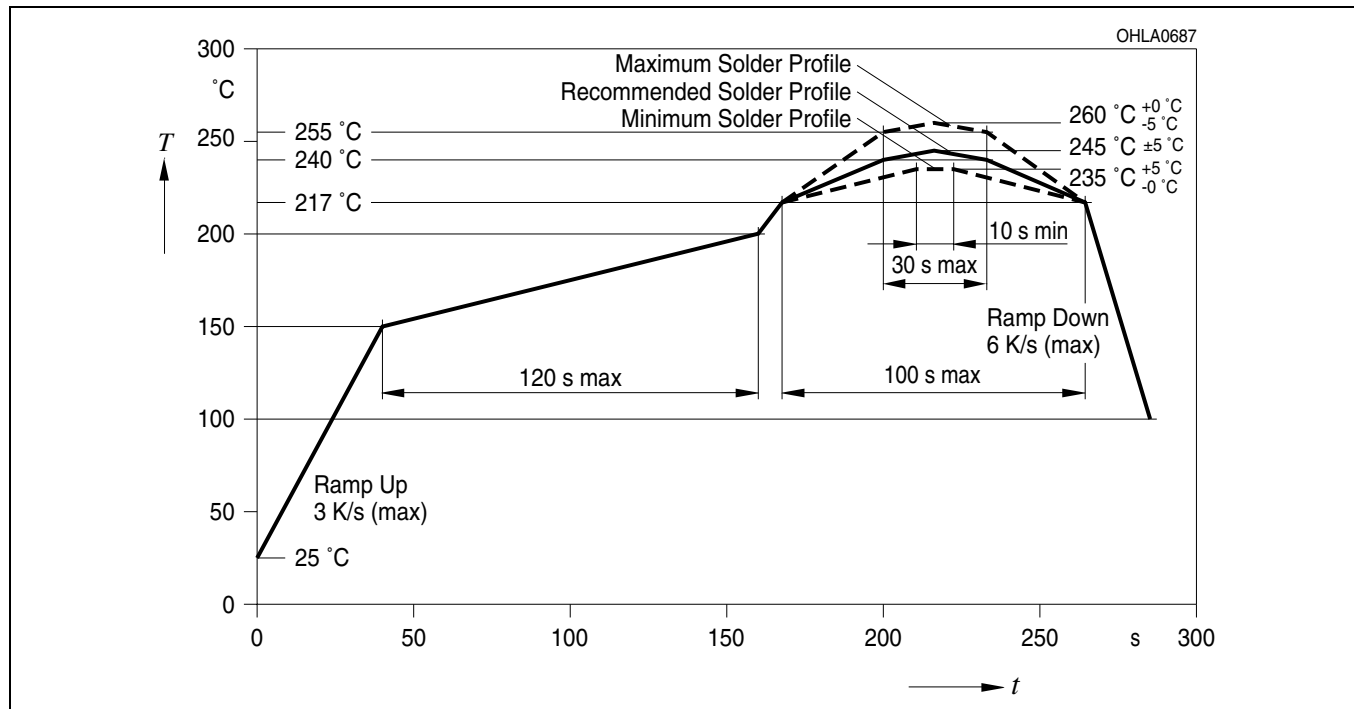
Reflow Löten
 Reflow Soldering



Maße in mm (inch) / Dimensions in mm (inch).

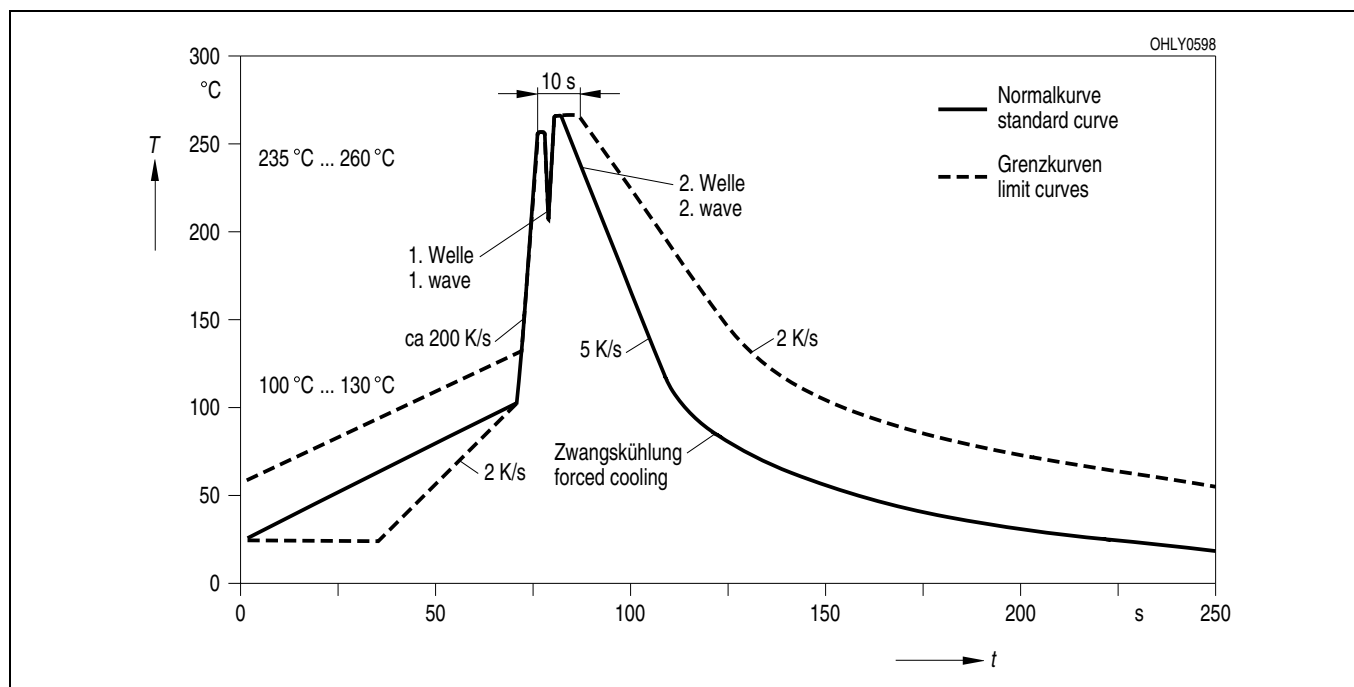
Lötbedingungen
Soldering Conditions
Reflow Lötprofil für bleifreies Löt
Reflow Soldering Profile for lead free soldering

Vorbehandlung nach JEDEC Level 2
 Preconditioning acc. to JEDEC Level 2
 (nach J-STD-020C)
 (acc. to J-STD-020C)



Wellenlöt (TTW)
TTW Soldering

(nach CECC 00802)
 (acc. to CECC 00802)



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